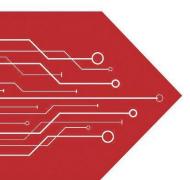
# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

**PLED** 

Product data sheet

www.msksemi.com



#### **Feature**

80W peak pulse power per line ( $t_P = 8/20\mu s$ )

SOD-523 package

Replacement for MLV(0603)

Bidirectional configurations

Protects one power or I/O port

Low clamping voltage

RoHS compliant

Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ±30kV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

## **Applications**

Cellular phones

Portable devices

Digital cameras

Power supplies

#### **Mechanical Characteristics**

Lead finish:100% matte Sn(Tin)

Mounting position: Any

Qualified max reflow temperature:260°C Device meets MSL 1 requirements

Pure tin plating: 7 ~ 17 um

Pin flatness: ≤3mil

# Pin1 Pin2 Circuit Diagram

SOD-523

### Electrical characteristics per line@25?( unless otherwisespecified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Working Voltage	V <sub>RWM</sub>				5	V
Breakdown Voltage	$V_{BR}$	I <sub>T</sub> = 1mA	5.8		7.8	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V T=25°C			1.0	μA
Clamping Voltage <sup>1)</sup>	V <sub>C</sub>	TLP = 16A, t <sub>p</sub> = 100ns		9.0		V
Dynamic resistance <sup>1)</sup>	R <sub>DYN</sub>			0.15		Ω
Clamping Voltage <sup>2)</sup>	Vc	I <sub>PP</sub> =10A		8	10	V
Junction Capacitance	СJ	V <sub>R</sub> =0V f = 1MHz		33		pF

#### Notes:

1.TLP parameter:  $Z_0$ =50 $\Omega$ ,  $t_0$ =100ns,  $t_r$ =2ns, averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A.

2. Non-repetitive current pulse, according to IEC61000-4-5.

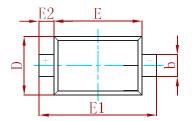
Absolute maximum rating@25?

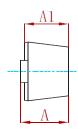
Rating	Symbol	Value	Unit
Peak Pulse Power (t <sub>p</sub> =8/20μs)	P <sub>pp</sub>	80	W
Operating Temperature	TJ	-55 to +150	°C
Storage Temperature	Tstg	-55 to +150	°C

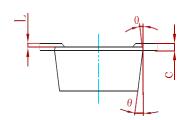






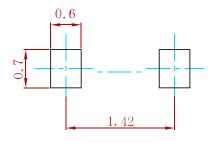






Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.510	0.770	0.020	0.031	
A1	0.500	0.700	0.020	0.028	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	0.750	0.850	0.030	0.033	
Е	1.100	1.300	0.043	0.051	
E1	1.500	1.700	0.059	0.067	
E2	0.200 REF		0.008 REF		
L	0.010	0.070	0.001	0.003	
0	7° I	REF	7° F	REF	

# **Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
MSESD5Z5CL	SOD-523	3000



Semiconductor

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